

SPECIFICATION









B1D06065K

650V ▲ 6A ▲ SiC SCHOTTKY DIODE

SILICON CARBIDE SIC SCHOTTKY DIODE ▲ THT type

Excellent surge capability

Easy paralleling due to positive V_F temperature coefficient

TO-220-2L package ▲ Epoxy meets UL94-V0

Low forward voltage

Temperature independent switching

Item (T _c = 25°C, unless otherwise noted)		Characteristics
Operating Temperature Range	Tı	-55°C to +175°C
Storage Temperature Range	Ts	-55°C to +175°C
Repetitive Peak Reverse Voltage	V_{RRM}	650V
Continuous Forward Current at T _C = 155°C	I _F	6A
Total Capacitive Charge (T _J = 25°C)	\mathbf{Q}_{C}	17nC
Capacitance Stored Energy (V _R = 400V)	Ec	4.5ய
Diode Forward Voltage (T _J = 175°C, I _F = 6A)	V_{F}	1.73V
Power Dissipation	P _{TOT}	98W

APPLICATIONS

EV Charging	Industrial Inverters	Motors & Drives	Power Factor Correction	Renewable Energy	SMPS	UPS
₹ /•			PFC	*		

PIN DESCRIPTION

Circuit Diagram	Outline • Front View	Pin No.	Description
Case 0 1 2	Case	1 2	Cathode (Case Backside) Anode

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ABSOLUT MAXIMUM RATINGS ▲ T_C = 25°C, unless otherwise noted

Item	Condition	Symbol		Unit
Repetitive Peak Reverse Voltage		V_{RRM}	650	V
Non-Repetitive Peak Reverse Voltage		V_{RSM}	650	V
Continuous Forward Current	T _C = 25°C	I _F	22	Α
Continuous Forward Current	$T_C = 155$ °C	I _F	6	Α
Non-Repetitive Forward Surge Current	T_C = 25°C, t_p = 10ms, Half Sine Wave	I _{FSM}	45	Α
I ² t Value	$T_C = 25^{\circ}C$, $t_p = 10$ ms	∫i²dt	10.12	A^2s
Power Dissipation	T _C = 25°C	P _{TOT}	98	W
Power Dissipation	$T_C = 110^{\circ}C$	P_{TOT}	42	W
Operating Junction Temperature		TJ	-55 to +175	°C
Storage Temperature Range		T_{STG}	-55 to +175	°C
TO-220 Mounting Torque	M3 Screw		0.7	Nm

ELECTRICAL CHARACTERISTICS

Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Static Characteristics						
DC Blocking Voltage	T _J = 25°C	V_{DC}	650			V
Diode Forward Voltage	$I_F = 6A, T_J = 25^{\circ}C$	V_{F}		1.43	1.60	V
Diode Forward Voltage	I _F = 6A, T _J = 175°C	V_{F}		1.73	2.80	V
Reverse Current	$V_R = 650V$, $T_J = 25$ °C	I_R		1	120	μΑ
Reverse Current	$V_R = 650V, T_J = 175$ °C	I _R		20	200	μΑ
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Dynamic Characteristics						
Dynamic Characteristics	V _R = 400V, T _J = 25°C					
Dynamic Characteristics Total Capacitive Charge	$V_{R} = 400V, T_{J} = 25^{\circ}C$ $Q_{C} = \int_{0}^{V_{R}} C(V) dV$	Qc		17		nC
		Q _c		17 271		nC pF
Total Capacitive Charge	$Q_C = \int_0^{V_R} C(V) dV$					
Total Capacitive Charge Total Capacitance	$Q_C = \int_0^{V_R} C(V) dV$ $V_R = 1V, f = 1MHz, T_J = 25^{\circ}C$	С		271		pF

THERMAL RESISTANCE PERFORMANCE

Item	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance, Junction to Case	$R_{\theta,JC}$		1.53		K/W



REFERENCE DATA A TYPICAL PERFORMANCE

Fig. 1 - Typical Forward Characteristics I_F vs. V_F

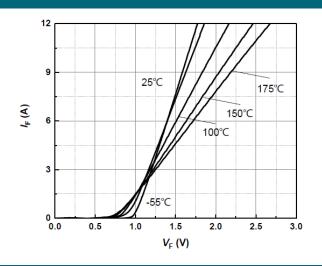


Fig. 2 • Typical Reverse Current I_R as function of Reverse Voltage V_R

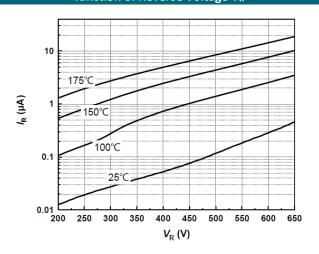


Fig. 3 • Diode Forward Current I_F as function of Case Temperature T_C (D = Duty Cycle)

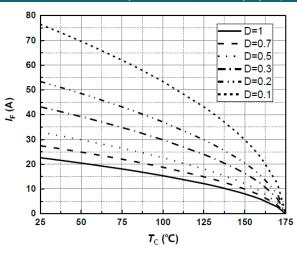


Fig. 4 • Typical Capacitance C as function of Reverse Voltage V_R , $C = f(V_R)$, $T_J = 25^{\circ}C$, f = 1MHz

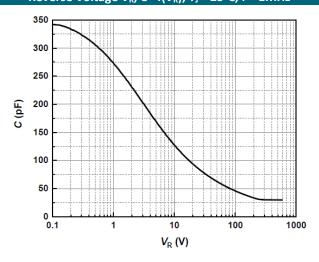


Fig. 5 • Typical Reverse Charge Q_C as function of Reverse Voltage V_R

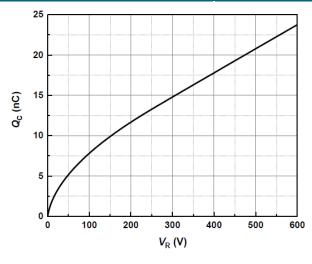
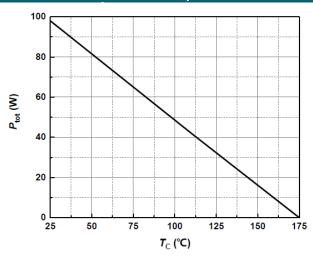


Fig. 6 • Power Dissipation P_{TOT} as function of Case Temperature T_C



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REFERENCE DATA A TYPICAL PERFORMANCE

Fig. 7 • Capacitance Stored Energy

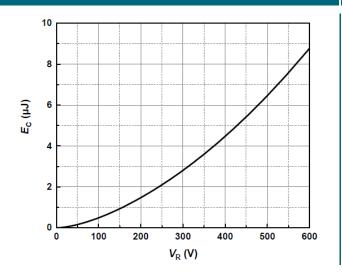
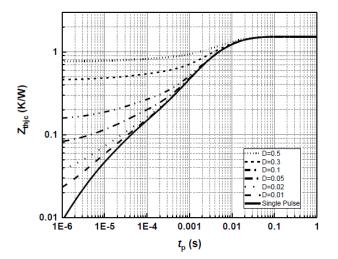
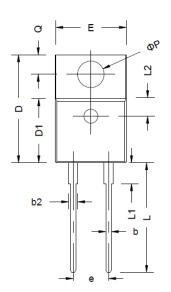


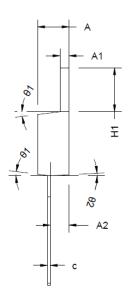
Fig. 8 • Maximum Transient Thermal Impedance, Z_{thjc} = f(t), Parameter: D = t/T

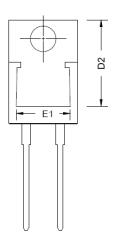


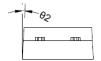


PACKAGE OUTLINE









Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
Α	4.37	4.57	4.77
A1	1.22	-	1.40
A2	2.49	2.69	2.89
b	0.75	-	0.96
b2	1.22	-	1.47
С	0.30	-	0.48
D	15.15	15.45	15.75
D1	9.05	9.15	9.25
D2	11.40	-	12.88
E	9.86	10.16	10.36

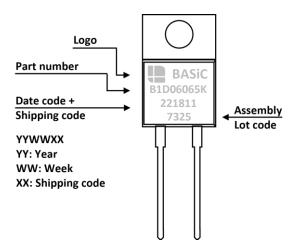
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)	
E1	6.86	-	8.89	
е	4.98	5.08	5.18	
H1	6.10	6.30	6.50	
L	12.70	-	13.70	
L1	-	-	4.10	
L2	2.50 REF			
ØΡ	3.70	3.84	3.99	
Q	2.54	-	2.94	
θ1	5°	7°	9°	
θ2	1°	3°	5°	

ORDERING INFORMATION

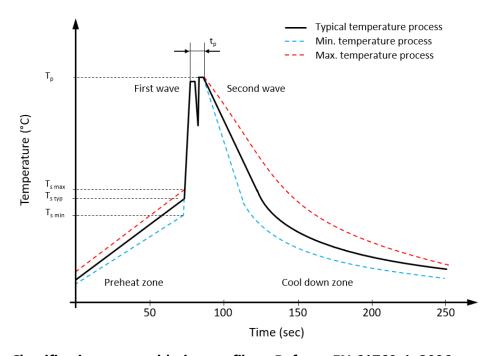
Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
B1D06065K	TO-220-2L	Tube	50pcs	500pcs	5,000pcs



PART MARKING



RECOMMENDED WAVE SOLDERING PROFILE & THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value ▲ Sn-Pb Assembly	Value ▲ Pb-free Assembly
Preheat temperature min.	$T_{s min}$	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	$T_{s max}$	130 °C	130 °C
Preheat time t_s from T_{smin} to T_{smax}	ts	70 seconds	70 seconds
Peak temperature	T_p	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	tp	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes

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REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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